# GaAlAs Infrared Emitting Diode



ODE-208-997B (Z)

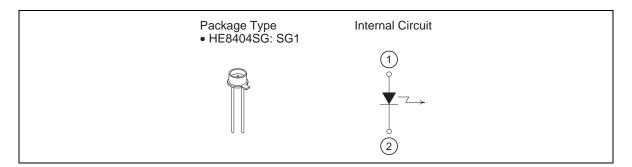
Rev.2 Mar. 2005

#### Description

The HE8404SG is a GaAlAs double heterojunction structure 820 nm band light emitting diode. It is suitable for use as the light source in a wide range of optical control and sensing equipment.

#### Features

• High efficiency and high output power





### **Absolute Maximum Ratings**

 $(T_{C} = 25^{\circ}C)$ 

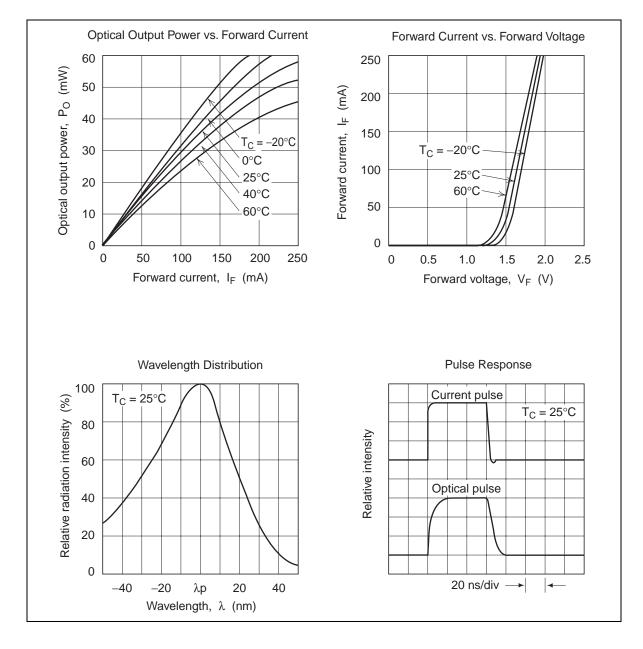
Item	Symbol	Value	Unit	
Forward current	I <sub>F</sub>	250	mA	
Reverse voltage	V <sub>R</sub>	3	V	
Operating temperature	Topr	–20 to +60	°C	
Storage temperature	Tstg	-40 to +90	°C	

# **Optical and Electrical Characteristics**

 $(T_{\rm C} = 25^{\circ}{\rm C})$ 

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Optical output power	Po	40		_	mW	I <sub>F</sub> = 200 mA
Peak wavelength	λρ	790	820	850	nm	I <sub>F</sub> = 200 mA
Spectral width	Δλ	_	50	60	nm	I <sub>F</sub> = 200 mA
Forward voltage	V <sub>F</sub>	_	_	2.5	V	I <sub>F</sub> = 200 mA
Reverse current	I <sub>R</sub>	—	—	100	μA	V <sub>R</sub> = 3 V
Capacitance	Ct	_	30	_	pF	V <sub>R</sub> = 0 V, f = 1 MHz
Rise time	t <sub>r</sub>	—	10	—	ns	I <sub>F</sub> = 50 mA
Fall time	t <sub>f</sub>		10		ns	I <sub>F</sub> = 50 mA

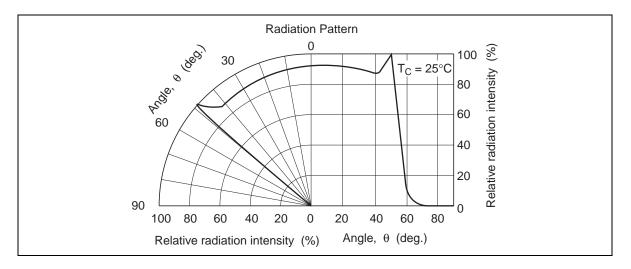




#### **Typical Characteristic Curves**

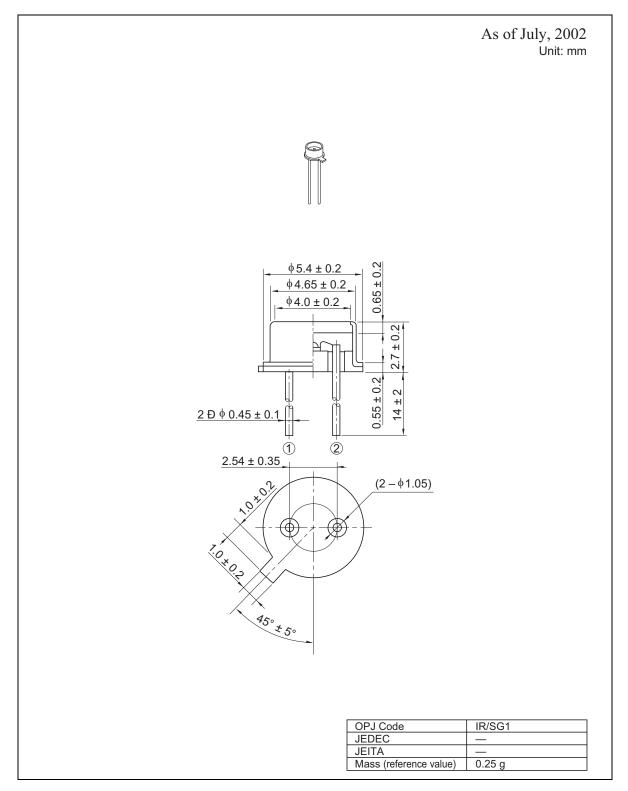


#### **Typical Characteristic Curves** (cont)





#### **Package Dimensions**





Rev.2, Mar. 2005, page 5 of 6

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#### **Sales Offices**



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